SM5551/SM5552



Low Pressure, Constant Current Low Pressure, Constant Voltage

Low Pressure Transducer Fully Temperature Compensated and Calibrated

DESCRIPTION

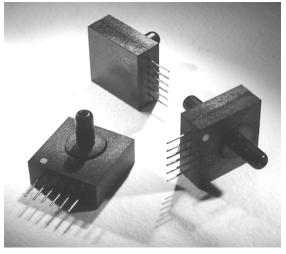
Pressure sensor models **SM5551** and **SM5552** are fully temperature-compensated and calibrated. Each sensor is housed in a rugged plastic enclosure.

Silicon Microstructures uses a unique silicon sensor chip structure to optimize low-pressure performance and to provide a true low-pressure sensor – not merely a derated high-pressure part. The result is a device that provides the performance necessary for low-pressure applications. Both constant current (model **SM5551**) and constant voltage (model **SM5552**) are available.

Factory calibration provides either a gain-set resistor (model **SM5551**) or a fixed 25mV full-scale output (model **SM5552**). By eliminating the need for customer gain adjustments, these parts are truly interchangeable and offer remarkable assembly-cost savings for a wide variety of OEM industrial, medical, and consumer products.

Rugged pins, sealed into the package to prevent breakage, allow simple placement in PC boards using standard 0.1 inch center-to center pin spacing. Full high-temperature plastic enclosure prevents substrate drift and eases handling.

Custom pressure ranges available in high-volume applications.



FEATURES

- Low pressure (from 0-0.15 PSI FS to 0-3.0 PSI FS)
- Differential or Gage Measurement
- Fully-enclosed, rugged plastic housing
- Fully Temperature-compensated
- Thoroughly Calibrated and Interchangeable
- Both Constant Voltage or Constant Current Drive Configuration Available
- Calibrated to Better than 2%

APPLICATIONS

- Medical equipment
- Respiration
- HVAC
- Level detection
- Flow measurement
- Industrial control

SM5551/SM5552

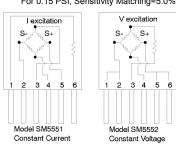
CHARACTERISTICS FOR SM5551/SM5552 - SPECIFICATIONS

Test Conditions: Model SM5501 w/excitation = 1.500mA @ 25 °C, Model SM5502 w/excitation = 10.00Vdc @ 25 °C, unless otherwise specified.

	Min.	Тур.	Max.	Units	Notes
Excitation					
Current (SM5551)	0.00	1.50	3.00	mA	
Voltage (SM5552)	0.00	10.00	20.00	V	
Output					
Span (SM5551)	25.0	45.0	75.0	mV	
Span (SM5552)	24.5	25.0	25.5	mV	1
Offset	-2.00	±0.20	2.00	mV	
Temperature Performance					
TC Span	-1.20	±0.20	1.20	%FS/100°C	2
TC Offset	-2.40	±0.20	2.40	%FS/100°C	2
Temp Hysteresis	-0.30	±0.05	0.30	%FS	3
Accuracy			1	•	
Linearity	-0.30	±0.05	0.30	%FS	4
Repeatability	-0.30	±0.05	0.30	%FS	
Pressure Hysteresis	-0.30	±0.05	0.30	%FS	
Sensitivity Matching	-2.00	±0.20	+2.00	%FS	5
Impedance (SM5501)			<u> </u>	J	
Z Input	2.20	3.00	3.80	kΩ	
Z Output	2.90	3.30	3.80	kΩ	
Impedance (SM5502)			<u> </u>	J	
Z Input	4.50	8.00	25.00	kΩ	
Z Output	2.00	2.50	3.80	kΩ	
Temperature Range			· L		1
Calibration	0		70	°C	
Operating	-40		125	°C	
Storage	-55		125	°C	
Dynamic Characteristics				<u> </u>	1
Proof Pressure	10X			FS Pressure	
Burst Pressure	15X			FS Pressure	

Notes:

- For the SM5552, 0.15 PSI range, span is 23.75 (min) to 26.25 (max). Measured over a temperature range of 0 to 70 °C. For explanation of RMS error, see application note AN5500. 2. For 0.15 PSI, TC Span=±3%FS/100 °C; TC Offset=±2.5%FS/100 °C
- For 0.30 PSI, Hysteresis=±0.45%FS; 3
 - For 0.15 PSI, Hysteresis=±0.65%FS
- Best fit straight line
 - For 0.30 PSI, Linearity=±0.5%FS; For 0.15 PSI, Linearity=±2.5%FS
- Sensitivity matching relates to part-to-part matching For 0.15 PSI, Sensitivity Matching=5.0%FS





1 -Signal Out 2 -Signal Out 3 V excitation 4 Ground 5 +Signal Out*

6 +Signal Out*

ORDERING INFORMATION: Excitation SM5551 - 015 - G 1: Current 2: Voltage Pressure Type D: Differential (2 Tubes) Excitation Pressure Pressure G: Gage (1 Tube) Other configurations available on large orders. Consult SMI for details.

. All dimensions are shown in inches - Tolerance on all dimensions <u>+</u> 0.005" unless otherwise specified.

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PSI	5551/ 5552		
0.15	001		
0.30	003		
0.80	800		
1.50	015		
3.00	030		

0.394

 0.09 ± 0.02



Ø0.189 Pin 1 Ø0.413 0.100 ->

Notice:
0.100

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^{*}Output increases as top-port pressure is increased